NITRO-SDK

Accessing Backup Devices in AGB Game Paks for Nintendo DS_™

Version 1.0.1

The contents in this document are highly confidential and should be handled accordingly.

NTR-06-0439-001-A Released: June 5, 2006

Confidential

These coded instructions, statements, and computer programs contain proprietary information of Nintendo of America Inc. and/or Nintendo Company Ltd. and are protected by Federal copyright law. They may not be disclosed to third parties or copied or duplicated in any form, in whole or in part, without the prior written consent of Nintendo.

Table of Contents

| 1 Introduct | ion | 5 |
|-------------|--|----|
| 2 How to A | ccess the Devices | 6 |
| | s for AGB Backup Access Functions | |
| _ | Backup Access Functions | |
| | ctions common to all AGB backup devices | |
| 4.1.1 | Function Reference (common to all devices) | |
| | Kbit SRAM | |
| 4.2.1 | Function Reference (for SRAM devices) | |
| | Kbit, 1Mbit Flash | |
| 4.3.1 | Function Reference (for Flash devices) | |
| | | |
| | arts Depicting Access to Each Device | |
| 5.1 Flow | v Common to All Devices | 18 |
| 5.2 256 | Kbit SRAM | 19 |
| 5.3 512 | Kbit, 1Mbit FLASH | 20 |
| Tables | | |
| Table 2-1 | Device Access | |
| Table 4-1 | | |
| Table 4-2 | CTRDG_SetTaskThreadPriority | 9 |
| Table 4-3 | CTRDG_ReadAgbSram and CTRDG_ReadAgbSramAsync | 9 |
| Table 4-4 | CTRDG_WriteAgbSram and CTRDG_WriteAgbSramAsync | 10 |
| Table 4-5 | CTRDG_VerifyAgbSram and CTRDG_VerifyAgbSramAsync | 10 |
| Table 4-6 | CTRDG_WriteAndVerifyAgbSram and CTRDG_WriteAndVerifyAgbSramAsync | 11 |
| Table 4-7 | CTRDG_ReadAgbFlash and CTRDG_ReadAgbFlashAsync | 13 |
| Table 4-8 | B CTRDG_EraseAgbFlashChip and CTRDG_EraseAgbFlashChipAsync | 14 |
| Table 4-9 | PaseAgbFlashSector and CTRDG_EraseAgbFlashSectorAsync | 14 |
| Table 4-1 | 0 CTRDG_WriteAgbFlashSector and CTRDG_WriteAgbFlashSectorAsync | 15 |
| Table 4-1 | _ , , , | |
| Table 4-1 | 2 CTRDG_WriteAndVerifyAgbFlash and CTRDG_WriteAndVerifyAgbFlashAsync | 16 |
| Figures | | |
| Figure 4- | 1 Error Code Details | 17 |
| Figure 5- | 1 Common Flow | 18 |
| Figure 5- | | |
| Figure 5- | 3 512Kbit, 1Mbit FLASH Process | 20 |

3

Revision History

| Version | Revision Date | Description |
|---------|---------------|----------------------------|
| 1.0.1 | 4/7/2006 | Changes made in NITRO-SDK. |
| 1.0.0 | 12/27/2005 | Initial version. |

1 Introduction

The NITRO-SDK provides a set of APIs for accessing the backup device in the Game Boy Advance (AGB) Game Paks. This document describes how to use these APIs to access the backup device.

Please access the backup memory in the AGB Game Paks using the Nintendo-provided NITRO-SDK. DO NOT use your own programs for direct reading and writing.

Currently, APIs are available for the following backup memory devices:

- 256Kbit SRAM
- 512Kbit Flash
- 1Mbit Flash

4K and 64Kbit EEPROMs cannot be accessed from DS applications.

2 How to Access the Devices

The table shows how each kind of device is accessed. DO NOT use any method other than those described below.

Table 2-1 Device Access

| Device | Method for Reading | Minimum Unit for Reading | Method for Writing | Minimum Unit for Writing |
|--------|---|--------------------------------|---|--------------------------------|
| SRAM | CTRDG_ReadAgbSram CTRDG_ReadAgbSramAsync | 1 byte | CTRDG_WriteAgbSram CTRDG_WriteAgbSramAsync | 1 byte |
| FLASH | CTRDG_ReadAgbFlash CTRDG_ReadAgbFlashAsync | 1 byte | CTRDG_WriteAgbFlashSector CTRDG_WriteAgbFlashSectorAsync | 4 Kbytes |

To access a backup device in an AGB Game Pak, you must first determine the type and the storage capacity of that device. Until this is determined, do not use any of the backup memory-related functions (including CTRDG IdentifyAgbBackup).

To determine the type and the storage capacity of the backup memory device, first use the CTRDG_GetAgbMakerCode function to get the maker code. After determining which company made the device, use the CTRDG_GetAgbGameCode function to evaluate the game code to determine the type and the storage capacity of the backup memory.

Note: The current version of IS-NITRO-DEBUGGER cannot properly access the AGB backup device. In order to verify operations, you will need to use an actual DS console. A version of the IS-NITRO-DEBUGGER with this problem fixed is planned for release in the future.

3 Warnings for AGB Backup Access Functions

In addition to the content of this manual, the DS Programming Guidelines also contain important information, precautions, and rules regarding AGB backup memory. Be sure to read that document and follow its provisions when using the AGB backup access functions.

4 The AGB Backup Access Functions

This chapter describes the functions used to access AGB backup devices.

4.1 Functions common to all AGB backup devices

Whether the AGB is equipped with SRAM or Flash as the backup device, the device is assigned to the Game Pak RAM region (starting from 0x0A000000) in the memory map.

The AGB backup device access functions described in this manual have the following features:

- The wait cycle is adjusted internally by the functions; the developer does not need to worry about this factor.
- Each function is available in synchronous and asynchronous (*Async) versions. The asynchronous version is realized by executing the synchronous version in a thread created internally by the CTRDG Init function.

Important: DO NOT use any of the AGB backup device access functions until the application has determined that an appropriate device is mounted in the Game Pak. The CTRDG IdentifyAgbBackup function is not an exception.

4.1.1 Function Reference (common to all devices)

u16 CTRDG_IdentifyAgbBackup (CTRDGBackupType type)

Table 4-1 CTRDG_IdentifyAgbBackup

| Arguments | CTRDGBackupType Type | Type of Backup Device that is Mounted in NITRO-CTRDG | |
|-----------------|----------------------|---|-------------------|
| Return value | u16 result | Normal termination Identification error (when the appropriate device is not in the library) | ⇒ 0 ⇒ Non-zero |

This specifies the type of backup memory device that is mounted in NITRO-CTRDG.

If the backup device is a Flash device, the ID is read to determine which Flash device is mounted in the Game Pak. After the capacity of the Flash and the sector size is obtained, the access speed is configured and the appropriate functions for accessing the Flash are set. The obtained Flash data can be referenced using the global variable flashType *flash. For more information about flashType, please see the header file ctrdg flash.h.

This function must be called once before any data can be written to or read from the backup device.

If the backup memory device that is mounted in NITRO-CTRDG is a 256Kbit SRAM chip, set the argument to CTRDG_BACKUP_TYPE_SRAM. If the device is a 512Mbit SRAM, set the argument to CTRDG_BACKUP_TYPE_FLASH_512K. If the device is a 1Mbit Flash, set the argument to CTRDG_BACKUP_TYPE_FLASH_1M.

If the device cannot be identified, the function will generate an error and the AGB backup access functions will be unusable.

Note: Specifying CTRDG_BACKUP_TYPE_FLASH_512K or CTRDG_BACKUP_TYPE_FLASH_1M for the argument initiates a process of writing to the device. If the argument does not match the type of backup device actually mounted in NITRO-CTRDG, the backup data in that device might be destroyed.

void CTRDG_SetTaskThreadPriority(u32 priority)

Table 4-2 CTRDG_SetTaskThreadPriority

| Arguments | u32 priority | Priority of the Task Thread |
|--------------|--------------|-----------------------------|
| Return value | None | |

This changes the priority of the task thread that executes asynchronous functions.

4.2 **256Kbit SRAM**

SRAM is assigned to the Game Pak RAM region (starting from 0x0A000000) in the memory map.

The functions described in this manual for accessing SRAM have the following special features:

- These functions are used for both reading and writing. The minimum unit of access for both reading and writing is 1 byte.
- Even when the CTRDG_WriteAgbSram function is used to write to the backup memory device, there is no guarantee that the data was written correctly. To verify data was written correctly, execute CTRDG_VerifyAgbSram afterwards.

Important: All SRAM access functions internally lock the Game Pak bus for a fixed period.

4.2.1 Function Reference (for SRAM devices)

```
void CTRDG_ReadAgbSram (u32 src, void* dst, u32 size)
void CTRDG ReadAgbSramAsync (u32 src, void* dst, u32 size, CTRDG TASK FUNK callback)
```

Table 4-3 CTRDG ReadAgbSram and CTRDG ReadAgbSramAsync

| Arguments | u32 *src | Address (in memory map) of the Read Source in SRAM |
|-----------------|--------------------------|--|
| | Void *dst | Address (in memory map) of the Work region storing the data that was read |
| | u32 size | Read size, in units of bytes |
| | CTRDG_TASK_FUNK callback | The callback function called at the end of the Read process (Only for asynchronous function) |
| Return value | None | |

Takes the length of data specified by the size argument starting at the specified source SRAM address, and reads it into the Work region, starting from the dst address.

```
void CTRDG WriteAgbSram (u32 dst, const void* src, u32 size)
```

void CTRDG_WriteAgbSramAsync (u32 dst, const void* src, u32 size, CTRDG_TASK_FUNK
callback)

Table 4-4 CTRDG_WriteAgbSram and CTRDG_WriteAgbSramAsync

| Arguments | u32 *src | The Address of the Work Region for the Write Source | |
|-----------------|--------------------------|---|--|
| | void *dst | Address (in memory map) of the write destination in SRAM | |
| | u32 size | Write size, in bytes | |
| | CTRDG_TASK_FUNK callback | The callback function called at the end of the Write process (Only for asynchronous function) | |
| Return value | None | | |

Takes data from the Work region the length of the size argument and writes it to SRAM, starting from the address in dst.

```
u32 CTRDG_VerifyAgbSram (u32 tgt, const void* src, u32 size)
void CTRDG_VerifyAgbSramAsync (u32 tgt, const void* src, u32 size, CTRDG_TASK_FUNK callback)
```

Table 4-5 CTRDG_VerifyAgbSram and CTRDG_VerifyAgbSramAsync

| Arguments | u32 *tgt | Pointer to the SRAM Address (in the Memory Map) of the Verify Target (the Data of the Write Destination) | |
|--------------|--|--|--|
| | void *src | The pointer to the address of the Work region for the verify source (the original data). | |
| | u32 size | The verify size, in bytes | |
| | CTRDG_TASK_FUNK callback | The callback function called at the end of the Verify process (Only for asynchronous function) | |
| Return value | u32 errorAdr (Only for synchronous function) | Normal termination Verification error | \Rightarrow 0 \Rightarrow Error address on device side |

This function verifies the data from the Work region src address with the data at the SRAM tgt address, for the number of bytes specified in the size argument.

In the synchronous version of the function, 0 is returned if the verification process ends normally. If there is a verification error, the function returns the address where the error occurred.

In the asynchronous version of the function, you can determine whether the Verify process was successful by referencing the result member of the CTRDGTaskInfo structure, which is an argument of the callback function that returns after this routine is called.

```
u32 CTRDG_WriteAndVerifyAgbSram (u32 dst, const void* src, u32 size)
void CTRDG_WriteAndVerifyAgbSramAsync (u32 dst, const void* src, u32 size,
CTRDG_TASK_FUNK callback)
```

Table 4-6 CTRDG_WriteAndVerifyAgbSram and CTRDG_WriteAndVerifyAgbSramAsync

| Arguments | u32 *dst | Pointer to the Write Destination SRAM Address (in Memory Map) | |
|-----------------|--|--|---------------------------------------|
| | void *src | Address of the write source Work region | |
| | u32 size | Write size, in bytes | |
| | CTRDG_TASK_FUNK callback | The callback function called at the end of the WriteAndVerify process (Only for asynchronous function) | |
| Return value | u32 errorAdr (Only for synchronous function) | Normal termination Verification error | ⇒ 0 ⇒ Error address on device side |

This function performs an internal verification process with CTRDG_VerifyAgbSram after writing the data with CTRDG_WriteAgbSram. If there is an error, the function retries up to CTRDG AGB SRAM RETRY MAX times. The maximum number of retries is defined in ctrdg sram.h.

In the synchronous version of the function, 0 is returned if the verification process ends normally. If there is a verify error, the function returns the address where the error occurred.

In the asynchronous version of the function, determine whether the WriteAndVerify process was successful by referencing the result member of the CTRDGTaskInfo structure, which is an argument of the callback function that returns after this routine is called.

4.3 512Kbit, 1Mbit Flash

Flash is assigned to the Game Pak RAM region (0x0A000000 to 0xA00FFFF) in the memory map. A 1-Mbit Flash comprises of two banks of 512 Kbits.

To accommodate the varying types and specifications of Flash used in Game Paks, the 512 Kbits are logically divided into 16 sectors of 32 Kbits (4 Kbytes) each and the Flash device is accessed in units of these sectors.

The functions for accessing Flash have the following special features:

- The access functions described in this manual are used for both reading and writing. The minimum unit of access is 1 byte for reading and one sector (4 KB) for writing.
- If the device is a 1M Flash device, the functions handle bank switching internally; the developer does not need to worry about this factor.
- Even if the CTRDG_WriteAgbFlashSector function ends normally, there is no guarantee that the data was written correctly. To verify whether the data was written correctly, execute CTRDG VerifyAgbFlash.

Important: Precautions regarding the use of the Flash access functions:

Processes required prior to using access functions (common to 512K and 1M Flash)

DO NOT use any of the Flash functions until the application has determined that a Flash device is mounted in the Game Pak and the capacity of that device (either 512 Kbits or 1 Mbit) has been determined. This rule applies even to the CTRDG IdentifyAgbBackup function.

• The operations of the access functions (common to 512K and 1M Flash)

Presently, different makes of Flash can be used with a given game title. For this reason, the access functions are in a format that is common to all the makes of Flash. However, since different devices have different specifications, the internal operations of a given access function will differ depending on the make of Flash that exists in the Game Pak, and the function's execution times can differ substantially. Keep this in mind when developing your program and make sure that it operates properly regardless of the Flash manufacturer.

Reading after an erase operation was interrupted (common to 512K and 1M Flash)

For some makes of Flash, if the power is cut while data is being erased in a sector, the data in that sector might change every time it is read in the future and subsequent reads will be unstable. After the sector falls into this unstable read state, using VerifyFlash to verify the data after executing ReadFlash can generate an inequality error, with the data appearing different even when read from the same address a second time.

Erasing the sector can restore it from this unstable read state. Execute a function that includes a process to erase the unstable sector (e.g., CTRDG_EraseAgbFlash or CTRDG_WriteAgbFlashSector), then try initializing and restoring the data.

Interrupts (common to 512K and 1M Flash)

Be aware that the Flash access functions (including the CTRDG_IdentifyAgbBackup function) internally disable all interrupts and lock the Game Pak bus for a set amount of time. Because of this behavior, when calling a Flash access function, do not use DMAs which start automatically for timing-specific operations like Direct Sound, V & H blank synchronization, display synchronization, and Game Pak requests.

• Timeout process using ticks (common to 512K and 1M Flash)

The access functions listed below use tick counts for determining timeouts when accessing Flash. Be sure to call the OS InitTick function before calling any of them.

Pertinent functions:

```
CTRDG_IdentifyAgbBackup,
CTRDG_EraseAgbFlashChip, CTRDG_EraseAgbFlashChipAsync
CTRDG_EraseAgbFlashSector, CTRDG_EraseAgbFlashSectorAsync
CTRDG_WriteAgbFlashSector, CTRDG_WriteAgbFlashSectorAsync
```

CTRDG WriteAndVerifyAgbFlash, CTRDG WriteAndVerifyAgbFlashAsync

Memory Bank Verification Errors (1M Flash only)

1M Flash shares two 512Kbit banks in the Game Pak RAM region (0x0A000000 to 0xA00FFFF) in the memory map. Be aware that for the functions below, the returned address when there is a verification error does not contain bank information.

The functions that return a verify error address are:

```
CTRDG_VerifyAgbFlash
CTRDG_WriteAndVerifyAgbFlash
CTRDG_VerifyAgbFlashAsync
CTRDG_WriteAndVerifyAgbFlashAsync
```

Important: There is generally a limit to the number of times that data can be overwritten on a Flash device, so you need to be aware of the ways you save data. For example, do not incorporate routines for frequent saving at places such as the screen where parameters are entered and do not write frequently to memory during communications. And, of course, do not incorporate an auto-save function in the game that constantly overwrites the game data. If you do not adhere to these rules, the lifespan of the Flash device will be shortened considerably.

Tip: Stretch out the interval between data overwrites, and use a number of sectors rather than always writing to the same sector. This will reduce the number of overwrites to any one sector.

Comment: Flash devices used with the AGB have warranties that guarantee a maximum of 10,000 cycles of erasing and overwriting. If data is saved to the Flash device at a rate of 30 times a day, that translates to the short lifespan of around one year.

4.3.1 Function Reference (for Flash devices)

```
void CTRDG_ReadAgbFlash (u16 sec_num, u32 offset, u8* dst, u32 size)
void CTRDG_ReadAgbFlashAsync (u16 sec_num, u32 offset, u8* dst, u32 size,
CTRDG_TASK_FUNC callback)
```

Table 4-7 CTRDG_ReadAgbFlash and CTRDG_ReadAgbFlashAsync

| Arguments | u16 sec_num | Target Sector Number |
|--------------|--------------------------|--|
| | u32 offset | Offset in sector, in bytes |
| | u8 *dst | The address of the Work region storing the data that was read (Address in memory map) |
| | u32 size | Read size, in bytes |
| | CTRDG_TASK_FUNK callback | The callback function called at the end of the Read process (Only for asynchronous function) |
| Return value | None | |

Starting from the offset address inside the target sector number, this function takes *size* bytes of data from the Flash device, and reads it into the Work region starting from the dst address.

This function will operate normally even if the specified read size straddles a sector boundary.

```
ul6 CTRDG_EraseAgbFlashChip (void)
void CTRDG_EraseAgbFlashChipAsync (CTRDG_TASK_FUNC callback)
```

Table 4-8 CTRDG_EraseAgbFlashChip and CTRDG_EraseAgbFlashChipAsync

| Arguments | CTRDG_TASK_FUNK callback | The callback function called at the end of the EraseChip process (Only for asynchronous function) | |
|--------------|---|---|---|
| Return value | u16 result (see note 1) (Only for synchronous function) | Normal termination Chip erase timeout error Internal device error | \Rightarrow 0 \Rightarrow 0xc003 \Rightarrow 0xa003 (only for 1M Flash) |

This function completely erases the entire Flash chip.

In the asynchronous version of the function, you can determine whether the Erase process was successful by referencing the result member of the CTRDGTaskInfo structure, which is an argument of the callback function that returns after this routine is called.

```
u16 CTRDG_EraseAgbFlashSector (u16 sec_num)
void CTRDG_EraseAgbFlashSectorAsync (u16 sec_num, CTRDG_TASK_FUNC callback)
```

Table 4-9 EraseAgbFlashSector and CTRDG_EraseAgbFlashSectorAsync

| Arguments | u16 sec_num | Target sector Number | |
|--------------|---|---|--|
| | CTRDG_TASK_FUNK callback | The callback function called at the end of the EraseSector process (Only for asynchronous function) | |
| Return value | u16 result (see Note 1) (Only for synchronous function) | Normal termination Parameter error (secNo>0x0f) Sector erase timeout error Internal device error | $\begin{array}{l} \Rightarrow 0 \\ \Rightarrow 0x80ff \\ \Rightarrow 0xc002 \\ \Rightarrow 0xa002 \text{ (only for 1M Flash)} \end{array}$ |

This function erases one sector's worth of the target sector number's data.

Because this routine is called inside CTRDG_WriteAgbFlashSector, it does not normally need to be called before writing data.

In the synchronous version of the function, a parameter error is returned if the target sector number is out of range.

In the asynchronous version of the function, you can determine whether the Erase process was successful by referencing the result member of the CTRDGTaskInfo structure, which is an argument of the callback function that returns after this routine was called.

```
u16 CTRDG_WriteAgbFlashSector (u16 sec_num,u8 *src)
void CTRDG_WriteAgbFlashSectorAsync (u16 sec_num,u8 *src, CTRDG_TASK_FUNC callback)
```

Table 4-10 CTRDG_WriteAgbFlashSector and CTRDG_WriteAgbFlashSectorAsync

| Arguments | u16 sec_num | Target sector Number | |
|--------------|---|--|--|
| | u8 *src | Address of write source (Address in memory map) | |
| | CTRDG_TASK_FUNK callback | The callback function called at the end of the Write process (Only for asynchronous function) | |
| Return value | u16 result (see note 1) (Only for synchronous function) | Normal termination Parameter error (secNo>0x0f) Sector erase verification error Sector erase timeout error Internal device error when erasing Program timeout error Internal device error during program | $\begin{array}{l} \Rightarrow 0 \\ \Rightarrow 0x80ff \\ \Rightarrow 0x8004 \text{ (only for Sanyo's Flash)} \\ \Rightarrow 0xc002 \\ \Rightarrow 0xa002 \text{ (only for 1M Flash)} \\ \\ \Rightarrow 0xc001 \\ \Rightarrow 0xa001 \text{ (only for 1M Flash)} \end{array}$ |

This function takes one sector's worth of data (4Kbytes) from the source address and writes it to the target sector number.

This routine internally calls the CTRDG_EraseAgbFlashSector function to erase the sector before writing the data. A parameter error is returned if the target sector number is out of range.

You can determine the number of remaining bytes while this routine is executing by referencing the global variable flash remainder.

In the asynchronous version of the function, you can determine whether the Write process was successful by referencing the result member of the CTRDGTaskInfo structure, which is an argument of the callback function that returns after this routine is called.

```
u32 CTRDG_VerifyAgbFlash (u16 sec_num,u8 *src,u32 size)
void CTRDG_VerifyAgbFlashAsync (u16 sec_num,u8 *src,u32 size, CTRDG_TASK_FUNC callback)
```

Table 4-11 CTRDG_VerifyAgbFlash and CTRDG_VerifyAgbFlashAsync

| Arguments | u16 sec_num | Target sector No. | |
|--------------|--|--|--|
| | u8 *src | Address (in memory map) of verify source | |
| | u32 size | Verify size (bytes) | |
| | CTRDG_TASK_FUNK callback | The callback function called at the end of the Verify process (Only for asynchronous function) | |
| Return value | u16 errorAdr (Only for synchronous function) | Normal termination Verification error | \Rightarrow 0 \Rightarrow Error address on device side |

This function verifies data of *size* bytes in length from the source address with data in the target sector number.

The function will operate normally even if the specified verify size straddles a sector boundary.

In this function, 0 is returned if the verification process ends normally. If there is a verify error, the

function returns the address where the error occurred. Note that the routine does not include a parameter check.

In the asynchronous version of the function, you can determine whether the Verify process was successful by referencing the result member of the CTRDGTaskInfo structure, which is an argument of the callback function that returns after this routine is called.

```
u32 CTRDG_WriteAndVerifyAgbFlash (u16 sec_num, u8 *src,u32 verifysize)
void CTRDG_WriteAndVerifyAgbFlashAsync (u16 sec_num, u8 *src,u32 verifysize,
CTRDG_TASK_FUNC callback)
```

Table 4-12 CTRDG_WriteAndVerifyAgbFlash and CTRDG_WriteAndVerifyAgbFlashAsync

| Arguments | u16 sec_num | Target sector No. | | |
|--------------|---|---|---|--|
| | u8 *src | Address (in memory map) of read source | | |
| | u32 verifysize | Verify size (bytes) | | |
| | CTRDG_TASK_FUNK callback | The callback function called at the end of the WriteAndVerify process (Only for asynchronous function) | | |
| Return value | u16 result (see note 1) (Only for synchronous function) | Normal termination Parameter error (secNo>0x0f) Sector erase verification error Sector erase timeout error Internal device error when erasing Program timeout error Internal device error during program Verification error | ⇒ 0 ⇒ 0x80ff ⇒ 0x8004 (only for Sanyo's Flash) ⇒ 0xc002 ⇒ 0xa002 (only for 1M Flash) ⇒ 0xc001 ⇒ 0xa001 (only for 1M Flash) ⇒ Error address on device side | |

This function internally calls <code>CTRDG_VerifyAgbFlash</code> to verify <code>verifysize</code> bytes of data after writing data with <code>CTRDG_WriteAgbFlashSector</code>. In other words, even though one sector's worth of data is written, the specified verify size can be smaller than one sector and can straddle sectors.

If an error occurs, the function will retry up to CTRDG_AGB_FLASH_RETRY_MAX times (the maximum number of retries defined in ctrdg_flash.h).

If there is a write error, the 32-bit return value will include one of the above 16-bit error codes. If there is a verify error, the 32-bit return value will be the address of the error in the device. Be aware of this difference when checking error codes.

In the asynchronous version of the function, you can determine whether the WriteAndVerify process was successful by referencing the result member of the CTRDGTaskInfo structure, which is an argument of the callback function that returns after this routine is called.

Note: When an error occurs, error codes are returned in accordance to the structure shown below.

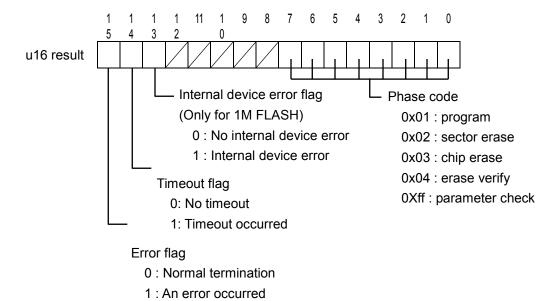


Figure 4-1 Error Code Details

5 Flow Charts Depicting Access to Each Device

This chapter presents flow charts that show the processes involved for accessing each backup memory device.

5.1 Flow Common to All Devices

The access functions are divided into groups based on the type of backup device. If functions inappropriate to a certain type of backup memory are used with that memory (for example, trying to use a Flash function to access SRAM), then this will become a source of bugs. This is why none of the access functions (including CTRDG_IdentifyAgbBackup) should be used until after the type of backup memory device and its storage capacity are determined.

To determine the type of backup memory device and its capacity, consult the following flow chart.

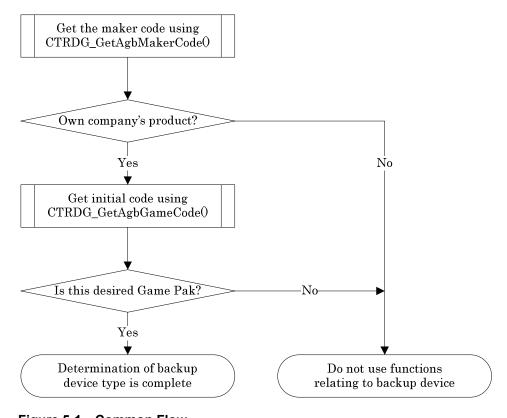


Figure 5-1 Common Flow

5.2 256Kbit SRAM

Before using SRAM access functions, first determine that the backup memory in the AGB Game Pak is an SRAM device. The process determining this is shown in the first flow chart.

After determining that the device type is SRAM, call the CTRDG_IdentifyAgbBackup function as shown Figure 5-2. After these processes are complete, the system is configured for proper reading and writing.

Preliminary processing

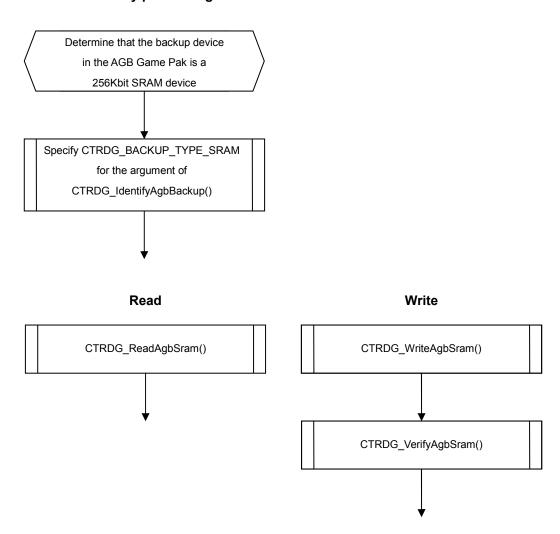


Figure 5-2 256Kbit SRAM Process

5.3 512Kbit, 1Mbit FLASH

Before using any of these Flash access functions, first ascertain whether the backup memory in the AGB Game Pak is a Flash device and determine its storage capacity (this is similar to the process shown in the first flow chart).

After determining it is a Flash device, call the CTRDG_IdentifyAgbBackup function as shown in Figure 5-3. Once complete, the system is configured for proper reading and writing.

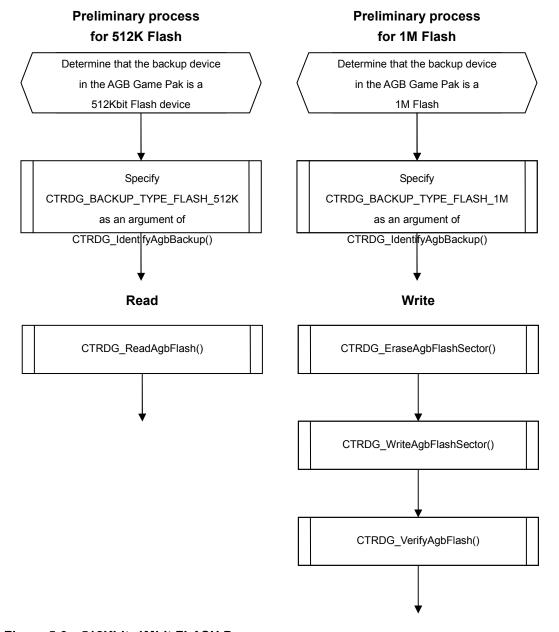


Figure 5-3 512Kbit, 1Mbit FLASH Process

NITRO-SDK Accessing Backup Devices in AGB Game Paks for DSAccessing Backup Devices in AGB Game Paks for DS

© 2005-2006 Nintendo

The contents of this document cannot be duplicated, copied, reprinted, transferred, distributed or loaned in whole or in part without the prior approval of Nintendo.